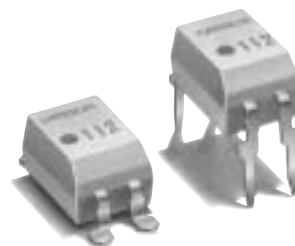


MOS FET Relays

G3VM-61A1/D1

Compact, General-purpose, Analog-switching MOS FET Relay, with Dielectric Strength of 2.5 kVAC between I/O Using Optical Isolation

- Upgraded G3VM-61 A/D Series.
- Switches minute analog signals.
- Leakage current of 1 μ A max. when output relay is open.



NEW

Application Examples

- Measurement devices
- Security systems
- Amusement machines

Note: The actual product is marked differently from the image shown here.

List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	60 VAC	G3VM-61A1	100	---
	Surface-mounting terminals		G3VM-61D1		
			G3VM-61D1(TR)	---	1,500

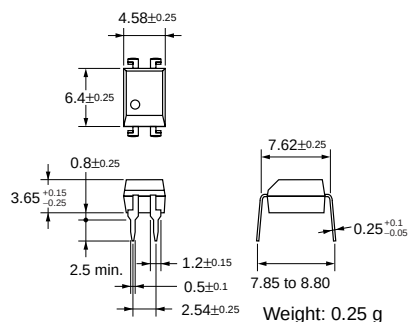
Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-61A1



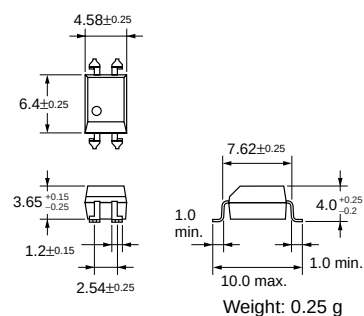
Note: The actual product is marked differently from the image shown here.



G3VM-61D1

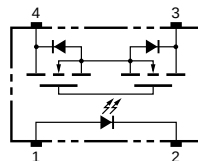


Note: The actual product is marked differently from the image shown here.

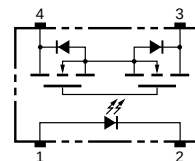


Terminal Arrangement/Internal Connections (Top View)

G3VM-61A1

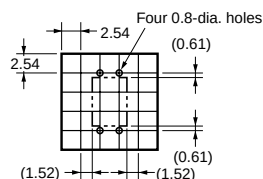


G3VM-61D1



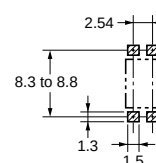
PCB Dimensions (Bottom View)

G3VM-61A1



Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61D1



■ Absolute Maximum Ratings (Ta = 25°C)

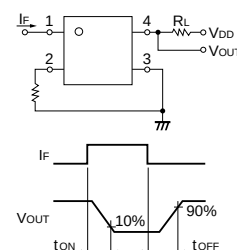
Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	I _F	50	mA
	Repetitive peak LED forward current	I _{FP}	1	A
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C
	LED reverse voltage	V _R	5	V
	Connection temperature	T _j	125	°C
Output	Output dielectric strength	V _{OFF}	60	V
	Continuous load current	I _O	500	mA
	ON current reduction rate	Δ I _{ON} /°C	-5.0	mA/°C
	Connection temperature	T _j	125	°C
Dielectric strength between input and output (See note 1.)		V _{I-O}	2,500	Vrms
Operating temperature		T _a	-40 to +85	°C
Storage temperature		T _{stg}	-55 to +125	°C
Soldering temperature (10 s)		---	260	°C

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item	Symbol	Minimum	Typical	Maximum	Unit	Measurement conditions
Input	LED forward voltage	V _F	1.0	1.15	1.3	V
	Reverse current	I _R	---	---	10	μA
	Capacity between terminals	C _T	---	30	---	pF
	Trigger LED forward current	I _{FT}	---	1.6	3	mA
Output	Maximum resistance with output ON	R _{ON}	---	1	2	Ω
	Current leakage when the relay is open	I _{LEAK}	---	---	1.0	μA
Capacity between I/O terminals		C _{I-O}	---	0.8	---	pF
Insulation resistance		R _{I-O}	1,000	---	---	MΩ
Turn-ON time		t _{ON}	---	0.8	2.0	ms
Turn-OFF time		t _{OFF}	---	0.1	0.5	ms

Note: 2. Turn-ON and Turn-OFF Times



■ Recommended Operating Conditions

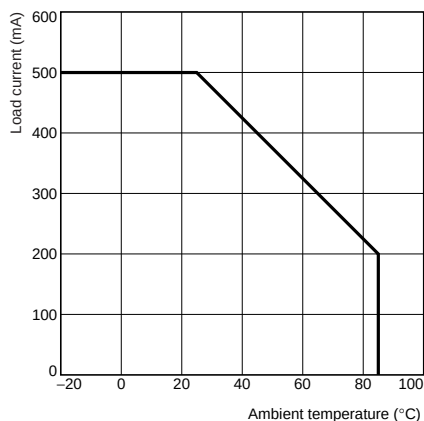
Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}	---	---	48	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	I _O	---	---	500	mA
Operating temperature	T _a	-20	---	65	°C

■ Engineering Data

Load Current vs. Ambient Temperature

G3VM-61A1(D1)



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.